

Performance

- Technology: 0.25um Power GaN HEMT
- Frequency: 11.2~11.8GHz
- Typical Pout : 58.5dBm
- Typical Gain: 8.5dB
- Typical PAE: 30%
- Bias: 70V/-1V
- Package: Metal Ceramic

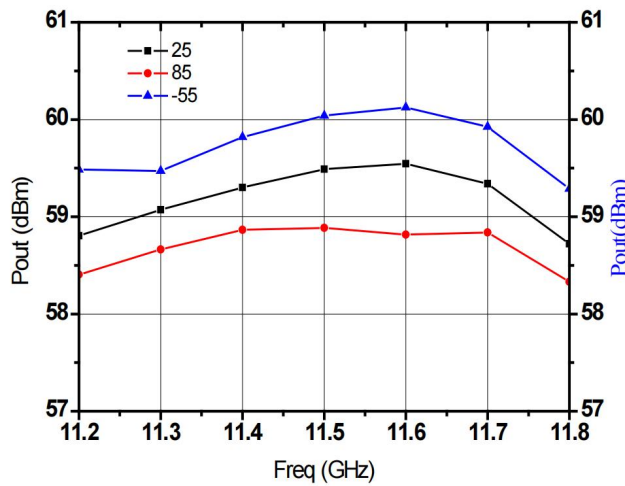


Electrical Specifications (TA=25°C, Vd=70V, PL=6us, D.C=0.1%, F: 11.2~11.8GHz)

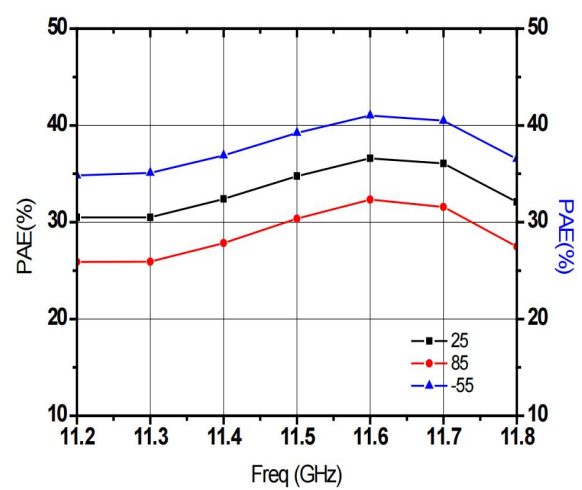
Symbol	Parameter	Min	Typical	Max	Unit
Pout	Output Power	58	58.5	-	dBm
Gp	Power Gain	8	8.5	-	dB
η_{add}	Power Added Efficiency	-	30	-	%
ΔGp	Gain Flatness	-0.8	-	+0.8	dB

Test Curves

Pout&Freq. @ Different Temp.



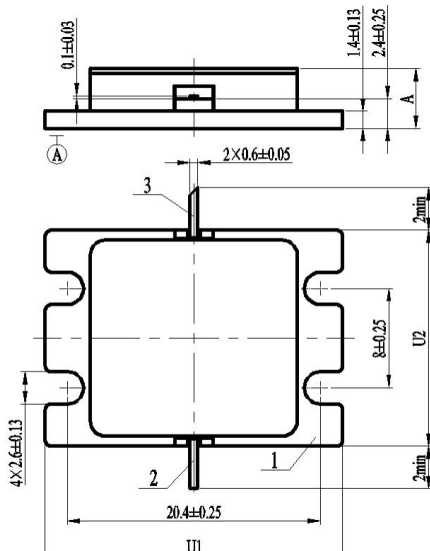
PAE&Freq. @ Different Temp.

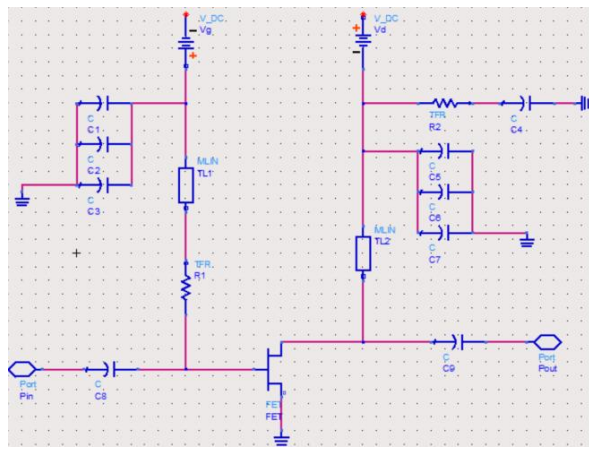


Absolute Max Ratings (T_A=25°C)

Symbol	Parameter	Value	Remark
V _d	Drain Voltage	100V	
V _g	Grid Voltage	-5V	
P _d	DC Dissipation	3000W	25°C
T _{ch}	Channel Temperature	225°C	【1】
T _m	Mounting Temperature	300°C	1 min, N ₂ Protection
T _{stg}	Storage Temperature	-55~175°C	

【1】 Exceeding any one or combination of these limits may cause permanent damage.

Outline Drawing	Dimension Symbol														
 The drawing consists of two views: a top view and a side view. The top view shows a square-like component with rounded corners and four protruding pins (labeled 1, 2, 3, and 4). Dimensions include overall width U1, overall height U2, pin spacing 20.4±0.25, pin width 4x2.6±0.13, and internal features like 2x0.6±0.05 and 8±0.25. The side view shows the component's profile with dimensions for height A, pin height 1.4±0.13, and base thickness 2.4±0.25. A tolerance of 0.1±0.03 is indicated for a specific feature.	<table><tr><th rowspan="2">Symbol</th><th colspan="2">Value (unit: mm)</th></tr><tr><th>Min.</th><th>Max.</th></tr><tr><td>U1</td><td>23.80</td><td>24.20</td></tr><tr><td>U2</td><td>17.20</td><td>17.60</td></tr><tr><td>A</td><td>-</td><td>5.2</td></tr></table>	Symbol	Value (unit: mm)		Min.	Max.	U1	23.80	24.20	U2	17.20	17.60	A	-	5.2
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Application Circuit	Recommended Value																												
	<table><tr><th>Parameter</th><th>Symbol</th><th>Value</th><th>Unit</th></tr><tr><td>Filter capacitor</td><td>C1,C2,C4, C5,C6</td><td>1000</td><td>pF</td></tr><tr><td>Filter capacitor</td><td>C3,C7</td><td>100</td><td>pF</td></tr><tr><td>DC isolation capacitance</td><td>C8,C9</td><td>1</td><td>pF</td></tr><tr><td>Stabilizing resistance</td><td>R1</td><td>15</td><td>Ω</td></tr><tr><td>Resistance</td><td>R2</td><td>50</td><td>Ω</td></tr><tr><td>Microstrip line</td><td>TL1,TL2</td><td>$\lambda/4$</td><td>-</td></tr></table>	Parameter	Symbol	Value	Unit	Filter capacitor	C1,C2,C4, C5,C6	1000	pF	Filter capacitor	C3,C7	100	pF	DC isolation capacitance	C8,C9	1	pF	Stabilizing resistance	R1	15	Ω	Resistance	R2	50	Ω	Microstrip line	TL1,TL2	$\lambda/4$	-
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Note:

- (1) This product is an internal matching tube, and the input and output impedance values are both 50 ohms;
- (2) Please strictly follow the order of adding negative electricity first and then positive electricity in the power-on sequence. When de-energizing, first reduce the drain voltage and then reduce the gate voltage;
- (3) This product is a high-power device. It is necessary to pay attention to heat dissipation during use. The higher the case temperature, the shorter the service life. It is advisable to use the temperature not higher than 80 degrees;
- (4) This product is an electrostatic sensitive device. It is necessary to pay attention to electrostatic protection during storage and use, and it needs to be well grounded when using it.